

Active

- 2 L1: (574) bit and first near magnetic adj layer
- 2 L2: (538) 1 and second near magnetic adj layer
- 2 L3: (4796) "3" and (non?magnetic non-magnetic nc)
- 2 L4: (276) 2 and (non?magnetic non-magnetic nonm)
- 2 L7: (76) 4 and 365/\$.ccls.
- 2 L8: (23) 4 and 438/\$.ccls.
- 2 L9: (22) 4 and 257/\$.ccls.
- 2 L10: (1328) (365/158,171,173).CCLS.
- 2 L11: (487) (438/48).CCLS.
- 2 L12: (1866) (257/295,421-427).CCLS.
- 2 L13: (1) 7 and 12
- 2 L14: (0) 7 and 11
- 2 L15: (61) 7 and 10

Failed

Saved

Saved Favorites

<input type="button" value="Browse"/>	<input type="button" value="Delete"/>	<input type="button" value="Clear"/>
<input checked="" type="checkbox"/> Dbs	USPAT;US-PATUS;EPD;JPO;DERWENT;IBM_TDB	
Default operator: OR		<input type="checkbox"/> Plurals
<input type="checkbox"/> Highlight all but terms actually		
7 and 10		

U	I	Document ID	Issue Date	Pages	Title	Current	Cur	Ref	Inventor	S	C	P	3
1	<input checked="" type="checkbox"/>	US 20030133323 A1	20030717	8	Magnetoresistive memor	365/158			Nejad, Hasan	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
2	<input checked="" type="checkbox"/>	US 20030112655 A1	20030619	26	Magnetic memory device	365/158	365/		Hosotani, Keiji	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
3	<input checked="" type="checkbox"/>	US 20030090932 A1	20030515	18	ASYMMETRIC MRAM	365/158			Deak, James G.	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
4	<input checked="" type="checkbox"/>	US 20030067800 A1	20030410	21	Magnetoresistive element	365/158			Koganei, Akio	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
5	<input checked="" type="checkbox"/>	US 20030063491 A1	20030403	11	Magneto resistive film, m	365/158	365/		Ikeda, Takashi	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
6	<input checked="" type="checkbox"/>	US 20030048658 A1	20030313	8	Magnetic element with a	365/158			Chen, Eugene Youj	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
7	<input checked="" type="checkbox"/>	US 20030002330 A1	20030102	18	Magnetoresistive element	365/158			Nishimura, Naoki	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
8	<input checked="" type="checkbox"/>	US 20020196657 A1	20021226	24	Magnetic memory device	365/158			Katoh, Yuukoh	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>
9	<input checked="" type="checkbox"/>	US 20020191437 A1	20021219	18	Magnetic memory device	365/158	365/		Yamada, Kouichi	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>